

# BRD3N50F

Rev.A Apr.-2024

## 描述 / Descriptions

TO-252 塑封封装 N 沟道 MOS 场效应管。  
N-CHANNEL MOSFET in a TO-252 Plastic Package.

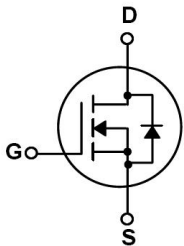
## 特征 / Features

$V_{DS}=500V$      $I_D=3A$   
 $R_{DS(ON)}@10V \leq 3.5\Omega$  (Typ.  $2.2\Omega$ )  
快速开关。Fast Switching.  
无卤产品。HF Product.

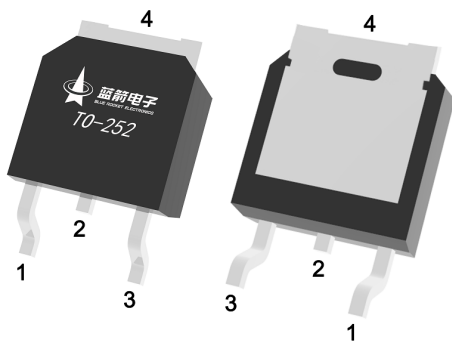
## 用途 / Applications

该器件非常适合适配器和充电器的电源开关电路，集成快速恢复二极管。  
These devices are well suited for power switch circuit of adaptor and charger, intergrate fast recovery diode.

## 内部等效电路 / Equivalent Circuit



## 引脚排列 / Pinning



PIN 1 : G

PIN 2 : D

PIN 3 : S

PIN 4 : D

## 印章代码 / Marking

见印章说明。  
See Marking Instructions.

**极限参数 / Absolute Maximum Ratings(Ta=25°C)**

参数 Parameter	符号 Symbol	数值 Rating	单位 Unit
Drain-Source Voltage	$V_{DSS}$	500	V
Drain Current	$I_D(T_C=25^\circ C)$	3	A
Drain Current - Pulsed	$I_{DM}$	6	A
Gate-Source Voltage	$V_{GS}$	$\pm 30$	V
Single Pulsed Avalanche Energy	$E_{AS}$	115.6	mJ
Avalanche Current	$I_{AS}$	5.1	A
Power Dissipation	$P_D(T_C=25^\circ C)$	45	W
Operating and Storage Temperature Range	$T_J, T_{STG}$	-55 to 150	$^\circ C$
Junction to Ambient	$R_{\theta JA}$	100	$^\circ C/W$
Junction to Case	$R_{\theta JC}$	2.78	$^\circ C/W$

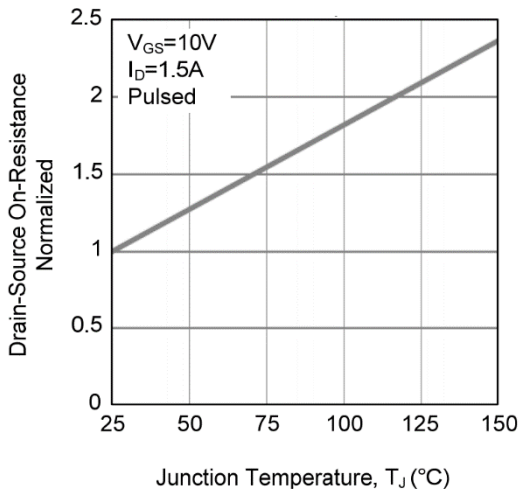
**电性能参数 / Electrical Characteristics(Ta=25°C)**

参数 Parameter	符号 Symbol	测试条件 Test Conditions	最小值 Min	典型值 Typ	最大值 Max	单位 Unit
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0V$ $I_D=250\mu A$	500			V
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=500V$ $V_{GS}=0V$			1	$\mu A$
Gate-Body Leakage Current Forward	$I_{GSS}$	$V_{GS}=\pm 30V$ $V_{DS}=0V$			$\pm 100$	nA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ $I_D=250\mu A$	2.0		4.0	V
Static Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=10V$ $I_D=1.5A$		2.2	3.5	$\Omega$
Drain-Source Diode Forward Voltage	$V_{SD}$	$V_{GS}=0V$ $I_S=3.0A$			1.4	V
Input Capacitance	$C_{iss}$	$V_{DS}=25V$ $V_{GS}=0V$ $f=1.0MHz$		260		pF
Output Capacitance	$C_{oss}$			135		
Reverse Transfer Capacitance	$C_{rss}$			4		
Total Gate Charge	$Q_G$	$V_{DS}=400V$ $I_D=3.0A$ $V_{GS}=10V$		12.5		nC
Gate-Source Charge	$Q_{GS}$			3.2		
Gate-Drain Charge	$Q_{GD}$			4.2		

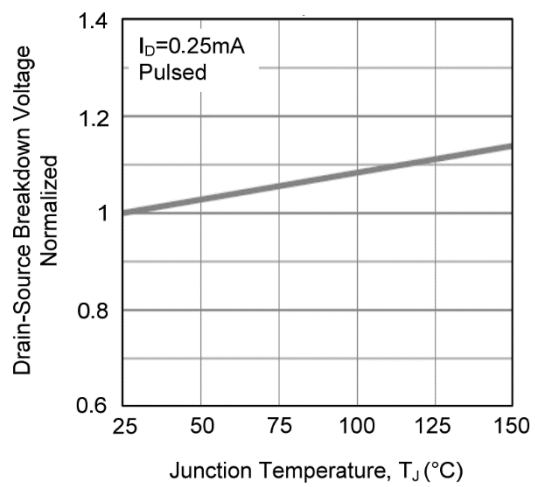
## 电性能参数 / Electrical Characteristics(Ta=25°C)

参数 Parameter	符号 Symbol	测试条件 Test Conditions	最小值 Min	典型值 Typ	最大值 Max	单位 Unit
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=100V$ $I_D=3.0A$ $V_{GS}=10V$ $R_G=25\Omega$		5.2		ns
Turn-On Rise Time	$t_r$			20.3		
Turn-Off Delay Time	$t_{d(off)}$			45		
Turn-Off Fall Time	$t_f$			28		
Maximum Continuous Drain-Source Diode Forward Current	$I_S$				3	A
Maximum Pulsed Drain-Source Diode Forward Current	$I_{SM}$				6	A
Reverse Recovery Time	$t_{rr}$	$V_{GS}=0V$ $I_S=3.0A$ $dI_F/dt=100 A/\mu s$		84		ns
Reverse Recovery Charge	$Q_{rr}$			0.8		$\mu C$

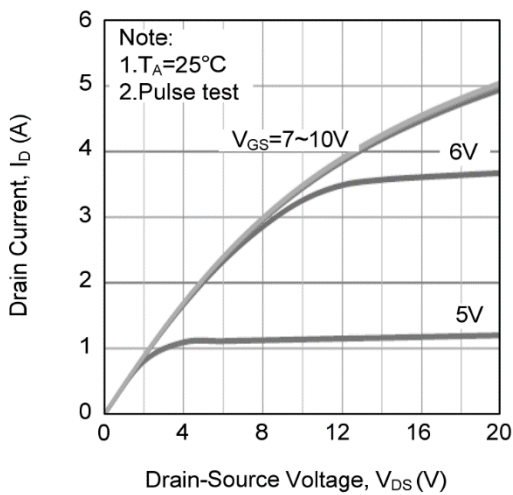
**电参数曲线图 / Electrical Characteristic Curve**



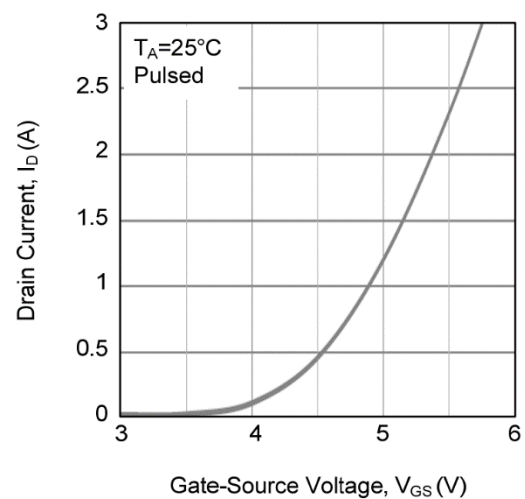
1. Drain-Source On-Resistance vs. Junction Temperature



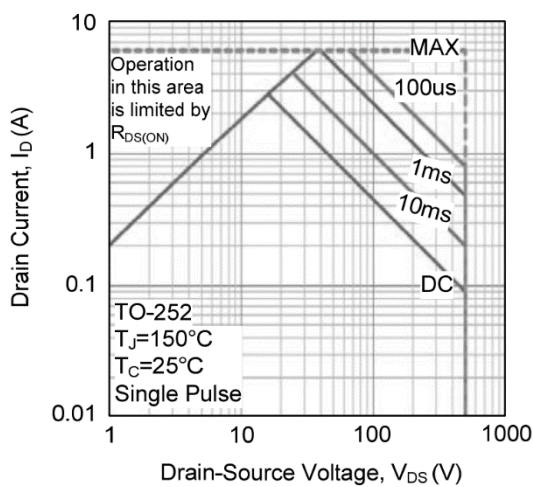
2. Breakdown Voltage vs. Junction Temperature



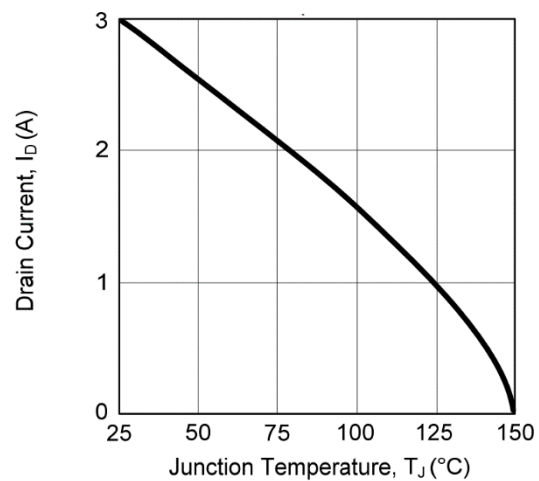
3. Drain Current vs. Drain-Source Voltage



4. Drain Current vs. Gate-Source Voltage

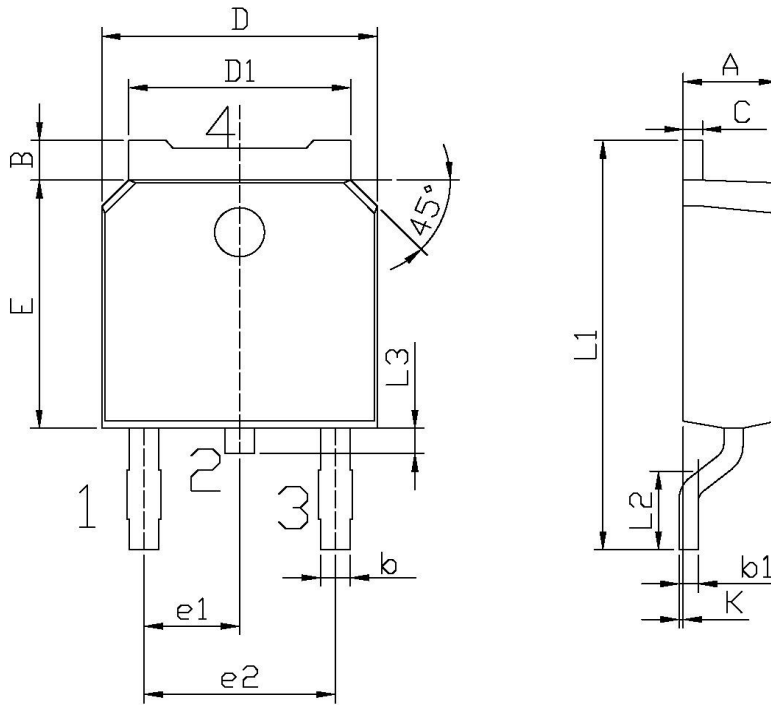


5. Safe Operating Area



6. Drain Current vs. Junction Temperature

**外形尺寸图 / Package Dimensions**

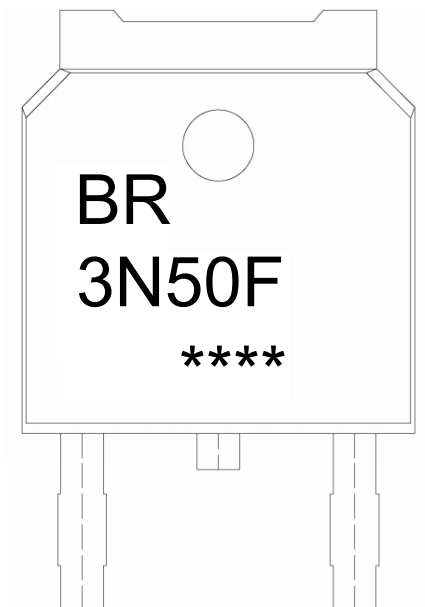


单位: mm

Symbol	Dimensions In Millimeters		Symbol	Dimensions In Millimeters	
	Min	Max		Min	Max
A	2.20	2.40	E	5.95	6.25
B	0.95	1.25	e1	2.24	2.34
b	0.70	0.90	e2	4.43	4.73
b1	0.45	0.55	L1	9.85	10.35
C	0.45	0.55	L2	1.70	2.00
D	6.45	6.75	L3	0.60	0.90
D1	5.10	5.50	K	0.00	0.10

TO-252

**印章说明 / Marking Instructions**



说明：

BR： 为公司代码

3N50F： 为型号代码

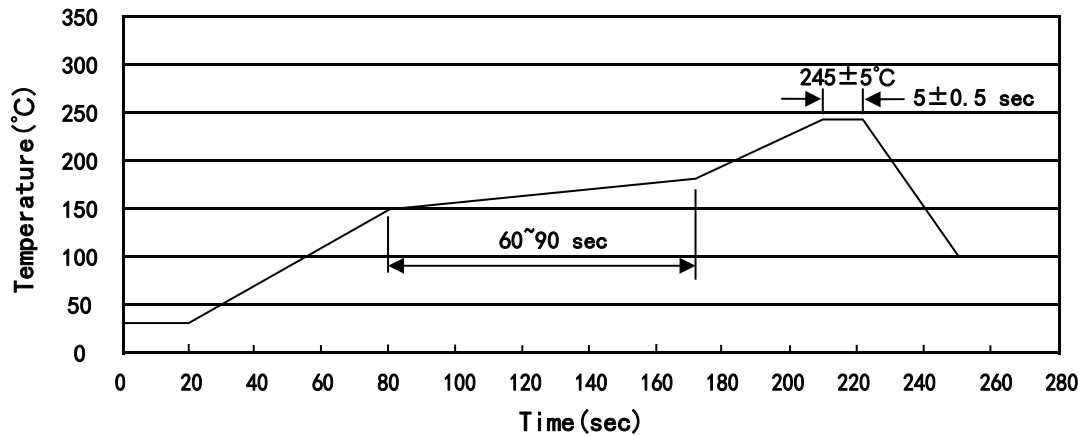
\*\*\*\*： 为生产批号代码，随生产批号变化

Note:

BR: Company Code

3N50F: Product Type Code

\*\*\*\*: Lot No. Code, code change with Lot No

**回流焊温度曲线图(无铅) / Temperature Profile for IR Reflow Soldering(Pb-Free)**


说明：

- 1、预热温度 150~180°C，时间 60~90sec；
- 2、峰值温度 245±5°C，时间持续为 5±0.5sec；
- 3、焊接制程冷却速度为 2~10°C/sec.

Note:

- 1.Preheating:150~180°C, Time:60~90sec.
- 2.Peak Temp.:245±5°C, Duration:5±0.5sec.
3. Cooling Speed: 2~10°C/sec.

**耐焊接热试验条件 / Resistance to Soldering Heat Test Conditions**

温度：260±5°C

时间：10±1 sec.

Temp.:260±5°C

Time:10±1 sec

**包装规格 / Packaging SPEC.**

卷盘包装 / REEL

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm <sup>3</sup> )		
	Units/Reel 只/卷盘	Reels/Inner Box 卷盘/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Reel	Inner Box 盒	Outer Box 箱
TO-252	2,500	2	5,000	6	30,000	13" ×16	360×360×50	380×335×366

套管包装 / TUBE

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm <sup>3</sup> )		
	Units/Tube 只/套管	Tubes/Inner Box 套管/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Tube 套管	Inner Box 盒	Outer Box 箱
TO-251/252	75	48	3,600	5	18,000	526×20.5×5.25	555×164×50	575×290×180

**使用说明 / Notices**